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# 3.3 V Dual LVTTL to Differential LVPECL Translator

#### **FEATURES**

- 450 ps (typ) Propagation Delay
- Operating Range: V<sub>CC</sub> 3.0 V to 3.8 with GND = 0 V
- <50 ps (max) Output to Output Skew</li>
- Built-in Temperature Compensation
- Drop in Compatible to MC100LVELT22

### **APPLICATIONS**

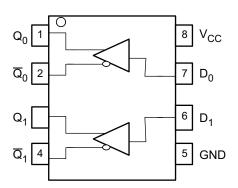
- Data and Clock Transmission Over Backplane
- Signaling Level Conversion for Clock or Data

### **DESCRIPTION**

The SN65ELT22 is a dual LVTTL to differential LVPECL translator buffer. It operates on +3V supply and ground only. The output is driven default high when the inputs are left floating or unused. The low output skew makes the device the ideal solution for clock or data signal translation.

The SN65LVELT22 is housed in an industry standard SOIC-8 package and is also available in TSSOP-8 package option.

#### **PINOUT ASSIGNMENT**



**Table 1. Pin Description** 

PIN	FUNCTION
D <sub>0</sub> , D <sub>1</sub>	TTL inputs
$Q_0, \overline{Q}_0, Q_1, \overline{Q}_1$	PECL/ECL outputs
V <sub>CC</sub>	Positive supply
GND	Ground

### ORDERING INFORMATION(1)

PART NUMBER	PART MARKING	PACKAGE	LEAD FINISH
SN65LVELT22D	SN65LVELT22	SOIC	NiPdAu
SN65LVELT22DGK	SN65LVELT22	SOIC-TSSOP	NiPdAu

(1) Leaded device options not initially available. Contact TI sales representative for further details.



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### **ABSOLUTE MAXIMUM RATINGS**(1)

		VALUE	UNIT
Absolute PECL mode supply voltage, V <sub>CC</sub>	GND = 0 V	6	V
V <sub>IN</sub> input voltage	V <sub>I</sub> ≤ V <sub>CC</sub>	6	V
Output ourrent	Continuous	50	A
Output current	Surge	100	mA mA
Operating temperature range		-40 to 85	°C
Storage temperature range		-65 to 150	°C

<sup>(1)</sup> Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### **POWER DISSIPATION RATINGS**

PACKAGE	CIRCUIT BOARD MODEL	POWER RATING T <sub>A</sub> < 25°C (mW)	THERMAL RESISTANCE, JUNCTION TO AMBIENT NO AIRFLOW	DERATING FACTOR T <sub>A</sub> > 25°C (mW/°C)	POWER RATING T <sub>A</sub> = 85°C (mW)
SOIC	Low-K	719	139	7	288
	High-K	840	119	8	336
SOIC-TSSOP	Low-K	469	213	5	188
	High-K	527	189	5	211

### THERMAL CHARACTERISTICS

	PARAMETER	PACKAGE	VALUE	UNIT
$\theta_{JB}$	Junction-to Board Thermal Resistance	SOIC	79	°C/W
		SOIC-TSSOP	120	
$\theta_{JC}$	Junction-to Case Thermal Resistance	SOIC	98	°C/W
		SOIC-TSSOP	74	

### **KEY ATTRIBUTES**

CHARACTERISTICS	VALUE
Moisture sensitivity level	Level 1
Flammability rating (Oxygen Index: 28 to 34)	UL 94 V-0 at 0.125 in
ESD-HBM	4 kV
ESD-machine model	200 V
ESD-charge device model	2 kV
Meets or exceeds JEDEC Spec EIA/JESD78 latchup test	·

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## PECL DC CHARACTERISTICS<sup>(1)</sup> ( $V_{CC} = 3.3 \text{ V}$ , GND = 0.0 $V^{(2)}$

	CHARACTERISTICS -		−40°C			25°C			85°C		
			TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Icc	Power Supply Current		23	33		25	33		26	33	mA
V <sub>OH</sub>	Output HIGH Voltage (3)	2275	2317	2420	2275	2331	2420	2275	2343	2420	mV
V <sub>OL</sub>	Output LOW Voltage <sup>(3)</sup>	1490	1558	1680	1490	1556	1680	1490	1555	1680	mV

- (1) Device will meet the specifications after thermal balance has been established when mounted in a socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
- (2) Input parameters vary 1:1 with V<sub>CC</sub>. V<sub>CC</sub> can vary ±0.15 V
- (3) Outputs are terminated through a  $50-\Omega$  resistor to  $V_{CC} 2.0 \text{ V}$ .

# TTL DC CHARACTERISTICS<sup>(1)</sup> ( $V_{CC} = 3.3 \text{ V}$ ; $T_A = -40 ^{\circ}\text{C}$ to 85°C)

	CHARACTERISTIC	CONDITION	MIN	TYP MAX	UNIT
I <sub>IH</sub>	Input HIGH current	V <sub>IN</sub> = 2.7 V		20	μΑ
I <sub>IHH</sub>	Input HIGH current max	$V_{IN} = V_{CC}$		100	μΑ
I <sub>IL</sub>	Input LOW current	V <sub>IN</sub> = 0.5 V		-0.2	mA
$V_{IK}$	Input clamp diode voltage	$I_{IN} = -18 \text{ mA}$		-1.2	V
$V_{IH}$	Input HIGH voltage		2.0		V
V <sub>IL</sub>	Input LOW voltage			0.8	V

(1) Device will meet the specifications after thermal balance has been established when mounted in a socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

# AC CHARACTERISTICS $^{(1)}(V_{CC} = 3.3 \text{ V}; \text{ GND} = 0.0 \text{ V})$

CHARACTERISTIC			-40°C			25°C			85°C		
	CHARACTERISTIC		TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
f <sub>MAX</sub>	Max switching frequency (2), see Figure 5		1750			1750			1700		MHz
t <sub>PLH</sub> /t <sub>PHL</sub>	Propagation delay to output at 1.5V, see Figure 4	200	425	550	200	445	550	200	460	550	ps
	Within – device skew <sup>(3)</sup>		20	50		20	50		20	50	
t <sub>SKEW</sub>	Device-to-device skew <sup>(4)</sup>		30	100		30	100		30	100	ps
t <sub>JITTER</sub>	Random clock jitter (RMS)		0.5	1.0		0.5	1.0		0.5	1.0	ps
t <sub>r</sub> /t <sub>f</sub>	Output rise/fall times Q (20%-80%)	300		500	300		500	300		500	ps

- (1) Device will meet the specifications after thermal balance has been established when mounted in a socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
- (2) Maximum switching frequency measured at output amplitude of 300 mV<sub>pp</sub>.
- (3) This is measured between outputs under the identical transitions and conditions on any one device.
- (4) Device-Device Skew is defined as identical transitions at identical V<sub>CC</sub> levels.

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## **Typical Termination for Output Driver**

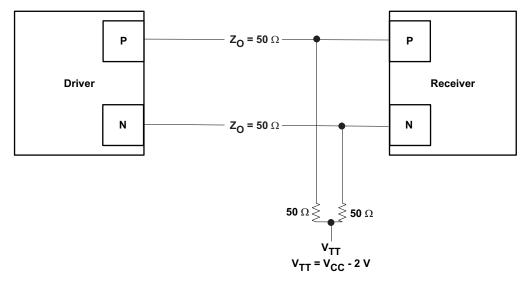


Figure 1. Termination for Output Driver

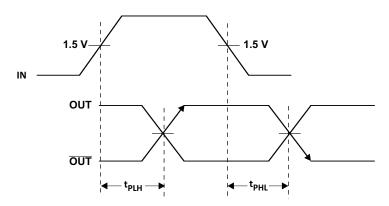


Figure 2. Output Propagation Delay



Figure 3. Output Rise and Fall Times

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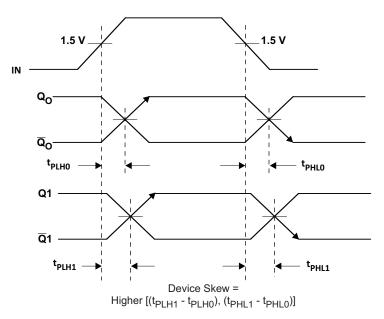


Figure 4. Device Skew

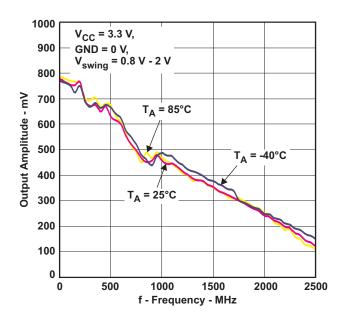


Figure 5. Output Amplitude vs. Frequency

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
SN65LVELT22D	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVEL22
SN65LVELT22D.B	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVEL22
SN65LVELT22DGK	Active	Production	VSSOP (DGK)   8	80   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SIRI
SN65LVELT22DGK.B	Active	Production	VSSOP (DGK)   8	80   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SIRI
SN65LVELT22DGKR	Active	Production	VSSOP (DGK)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SIRI
SN65LVELT22DGKR.B	Active	Production	VSSOP (DGK)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SIRI
SN65LVELT22DR	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVEL22
SN65LVELT22DR.B	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVEL22

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No. RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

## **PACKAGE OPTION ADDENDUM**

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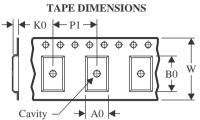
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## **PACKAGE MATERIALS INFORMATION**

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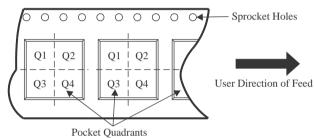
### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

	Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ĺ	SN65LVELT22DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
ĺ	SN65LVELT22DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

# **PACKAGE MATERIALS INFORMATION**

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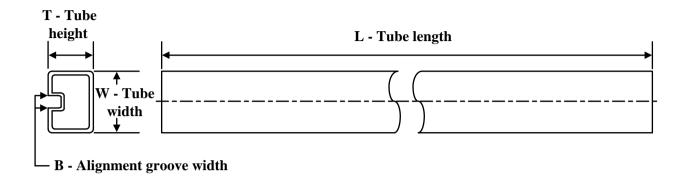
### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LVELT22DGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
SN65LVELT22DR	SOIC	D	8	2500	353.0	353.0	32.0

# **PACKAGE MATERIALS INFORMATION**

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### **TUBE**

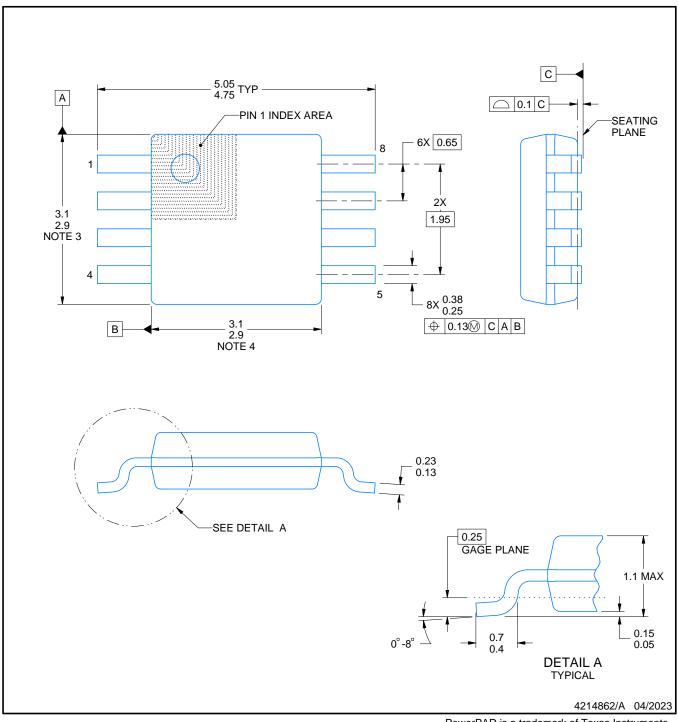


### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN65LVELT22D	D	SOIC	8	75	506.6	8	3940	4.32
SN65LVELT22D.B	D	SOIC	8	75	506.6	8	3940	4.32
SN65LVELT22DGK	DGK	VSSOP	8	80	330.2	6.6	3005	1.88
SN65LVELT22DGK.B	DGK	VSSOP	8	80	330.2	6.6	3005	1.88



SMALL OUTLINE PACKAGE



### NOTES:

PowerPAD is a trademark of Texas Instruments.

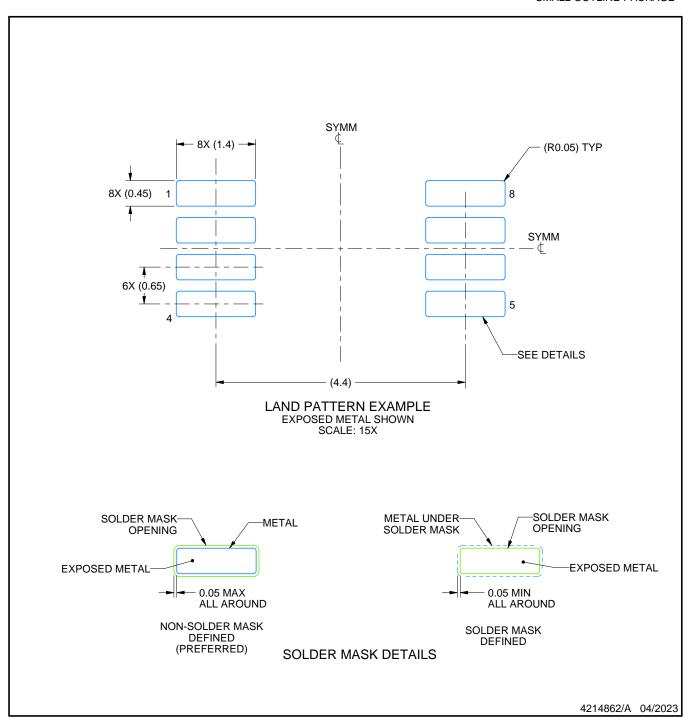
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



SMALL OUTLINE PACKAGE

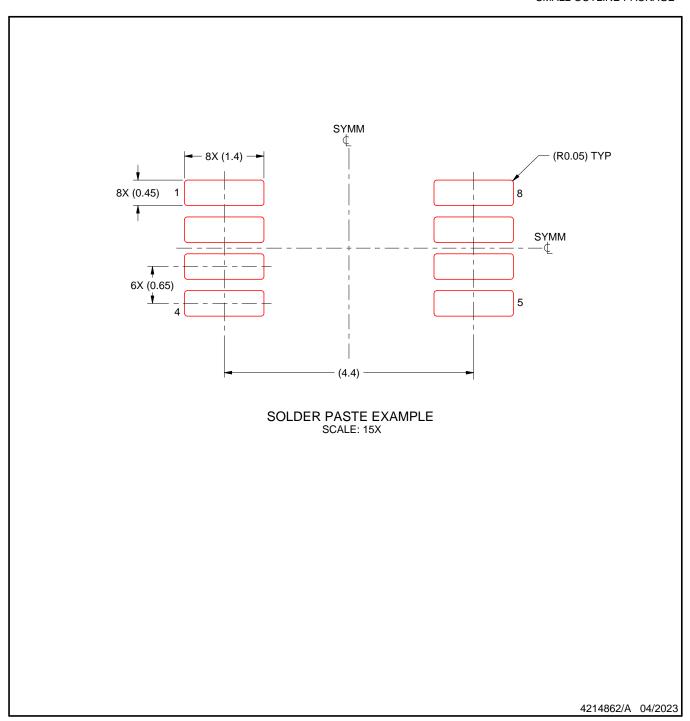


NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE INTEGRATED CIRCUIT



### NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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